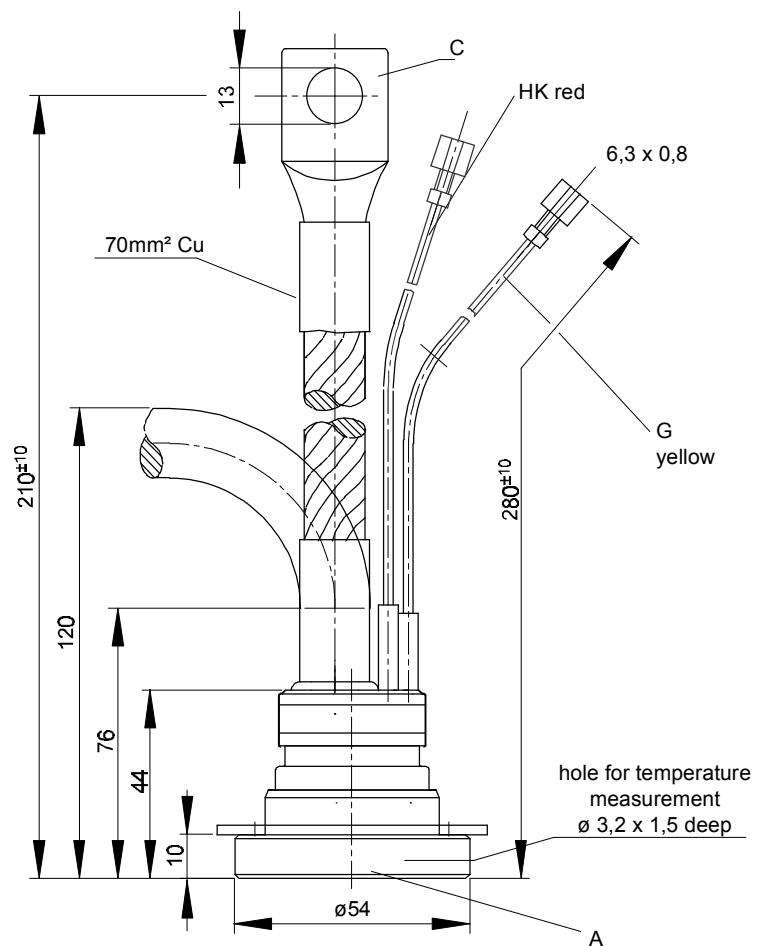




European Power-
Semiconductor and
Electronics Company

Marketing Information T 345 N



T 345 N

Elektrische Eigenschaften		Electrical properties				
<i>Höchstzulässige Werte</i>		<i>Maximum rated values</i>				
Periodische Vorwärts- und Rückwärts-Spitzenperrspannung	repetitive peak forward off-state and reverse voltages	$t_{vj} = -40^\circ\text{C} \dots t_{vj \max}$	V_{DRM}, V_{RRM}	600 800 1000 1200 1400 1600 1800 *	V	
Vorwärts-Stoßspitzenperrspannung	non-repetitive peak forward off-state voltage	$t_{vj} = -40^\circ\text{C} \dots t_{vj \max}$	$V_{DSM} = V_{DRM}$	600 800 1000 1200 1400 1600 1800 *	V	
Rückwärts-Stoßspitzenperrspannung	non-repetitive peak reverse voltage	$t_{vj} = +25^\circ\text{C} \dots t_{vj \max}$	$V_{RSM} = V_{RRM}$	700 900 1100 1300 1500 1700 1900	V	
Durchlaßstrom-Grenzeffektivwert	RMS on-state current		I_{TRMSM}	550	A	
Dauergrenzstrom	average on-state current	$t_c = 85^\circ\text{C}$	I_{TAVM}	345	A	
Stoßstrom-Grenzwert	surge current	$t_{vj} = 25^\circ\text{C}, t_p = 10 \text{ ms}$ $t_{vj} = t_{vj \max}, t_p = 10 \text{ ms}$	I_{TSM}	8000 6900	A	
Grenzlastintegral	$I^2 t$ -value	$t_{vj} = 25^\circ\text{C}, t_p = 10 \text{ ms}$ $t_{vj} = t_{vj \max}, t_p = 10 \text{ ms}$	$I^2 t$	320000 238000	$\text{A}^2 \text{s}$	
Kritische Stromsteilheit	critical rate of rise of on-state current	$v_D \leq 67\%, V_{DRM}, f = 50 \text{ Hz}$ $f = 50 \text{ Hz}, i_{GM} = 1 \text{ A}, di_G/dt = 1 \text{ A}/\mu\text{s}$	$(di_T/dt)_{cr}$	150	$\text{A}/\mu\text{s}$	
Kritische Spannungssteilheit	critical rate of rise of off-state voltage	$t_{vj} = t_{vj \max}, v_D = 67\% V_{DRM}$	$(dv/dt)_{cr}$	1000	$\text{V}/\mu\text{s}$	
Charakteristische Werte		Characteristic values				
Durchlaßspannung	on-state voltage	$t_{vj} = t_{vj \max}, i_T = 1000 \text{ A}$	v_T	max. 1,65	V	
Schleusenspannung	threshold voltage	$t_{vj} = t_{vj \max}$	$V_{T(TO)}$	0,85	V	
Ersatzwiderstand	slope resistance	$t_{vj} = t_{vj \max}$	r_T	0,75	$\text{m}\Omega$	
Zündstrom	gate trigger current	$t_{vj} = 25^\circ\text{C}, v_D = 6 \text{ V}$	I_{GT}	max. 200	mA	
Zündspannung	gate trigger voltage	$t_{vj} = 25^\circ\text{C}, v_D = 6 \text{ V}$	V_{GT}	max. 2	V	
Nicht zündender Steuerstrom	gate non-trigger current	$t_{vj} = t_{vj \max}, v_D = 6 \text{ V}$	I_{GD}	max. 10	mA	
Nicht zündende Steuerspannung	gate non-trigger voltage	$t_{vj} = t_{vj \max}, v_D = 0,5 V_{DRM}$	V_{GD}	max. 0,2	V	
Haltestrom	holding current	$t_{vj} = 25^\circ\text{C}, v_D = 6 \text{ V}, R_A = 5,6 \Omega$	I_H	max. 300	mA	
Einraststrom	latching current	$t_{vj} = 25^\circ\text{C}, v_D = 6 \text{ V}, R_{GK} \geq 10 \Omega$ $i_{GM} = 1 \text{ A}, di_G/dt = 1 \text{ A}/\mu\text{s}, t_g = 20 \mu\text{s}$	I_L	max. 1,2	A	
Vorwärts- und Rückwärts-Sperrstrom	forward off-state and reverse currents	$t_{vj} = t_{vj \max}, V_D = V_{DRM}, V_R = V_{RRM}$	i_D, i_R	max. 80	mA	
Zündverzug	gate controlled delay time	$t_{vj} = 25^\circ\text{C}, i_{GM} = 1 \text{ A}, di_G/dt = 1 \text{ A}/\mu\text{s}$	t_{gd}	max. 4	μs	
Freiwerdezeit	circuit commutated turn-off time	siehe Techn.Erl./see Techn. Inf.	t_q	typ. 250	μs	
Thermische Eigenschaften		Thermal properties				
Innerer Wärmewiderstand	thermal resistance, junction to case	$\Theta = 180^\circ \text{ el. sin DC}$	R_{thJC}	max. 0,08 max. 0,077	$^\circ\text{C}/\text{W}$	
Höchstzul. Sperrsichttemperatur	max. junction temperature		$t_{vj \max}$	125	°C	
Betriebstemperatur	operating temperature		$t_{c op}$	-40...+125	°C	
Lagertemperatur	storage temperature		t_{stg}	-40...+150	°C	
Mechanische Eigenschaften		Mechanical properties				
Si-Elemente mit Druckkontakt	Si-pellet with pressure contact					
Anpreßkraft	clamping force		F	5,5	kN	
Gewicht	weight		G	typ. 620	g	
Kriechstrecke	creepage distance			12	mm	
Feuchtekasse	humidity classification	DIN 40040			C	
Schwingfestigkeit	vibration resistance	$f = 50 \text{ Hz}$		50	m/s^2	
Maßbild, anliegend	outline, attached	DIN 41894-224 A4				

* Für größere Stückzahlen Liefertermin erfragen / Delivery for larger quantities on request

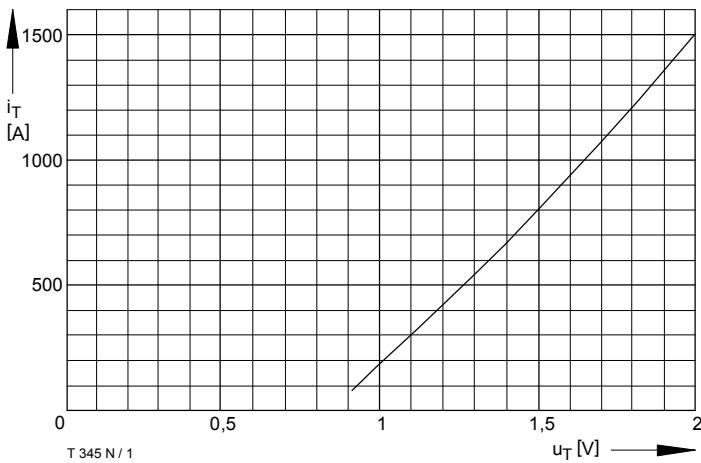


Bild / Fig. 1
Grenzdurchlaßkennlinie / Limiting on-state characteristic
 $i_T = f(u_T)$, $t_{vj} = t_{vj \max}$

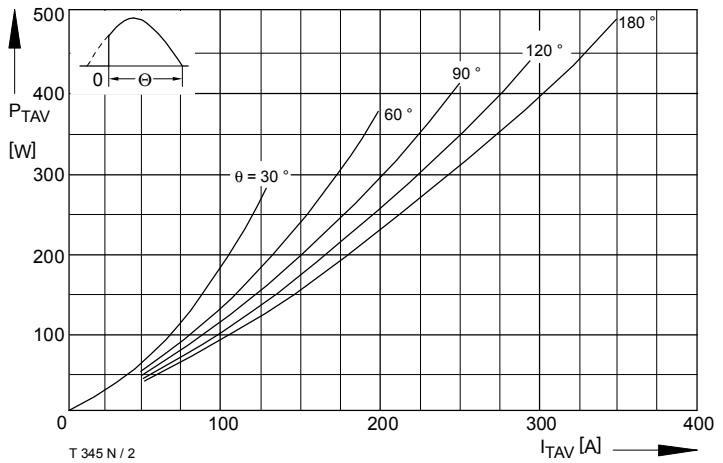


Bild / Fig. 2
Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
Parameter: Stromflußwinkel / Current conduction angle θ

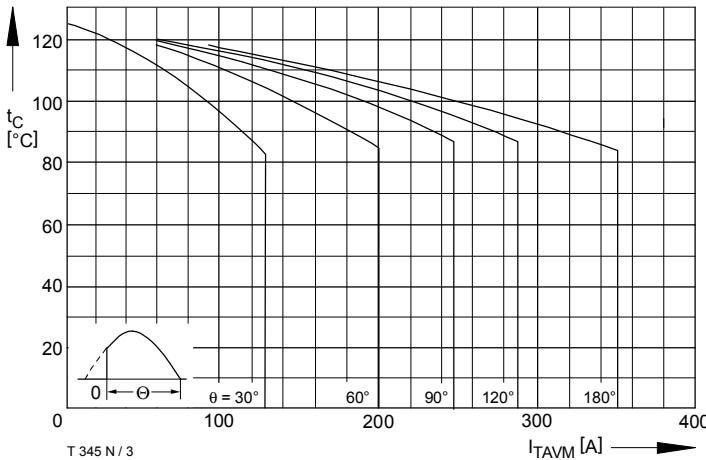


Bild / Fig. 3
Höchstzulässige Gehäusetemperatur / Max. allowable case temperature
 $t_C = f(I_{TAVM})$
Beidseitige Kühlung / Two-sided cooling
Parameter: Stromflußwinkel / Current conduction angle θ

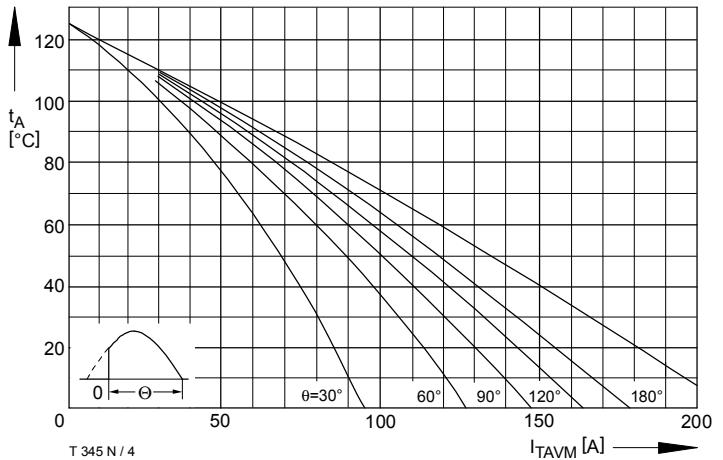


Bild / Fig. 4
Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $t_A = f(I_{TAVM})$
Luftselbstkühlung / Natural air cooling
Kühlkörper / Heatsink: KO.55-FB54-A
Parameter: Stromflußwinkel / Current conduction angle θ

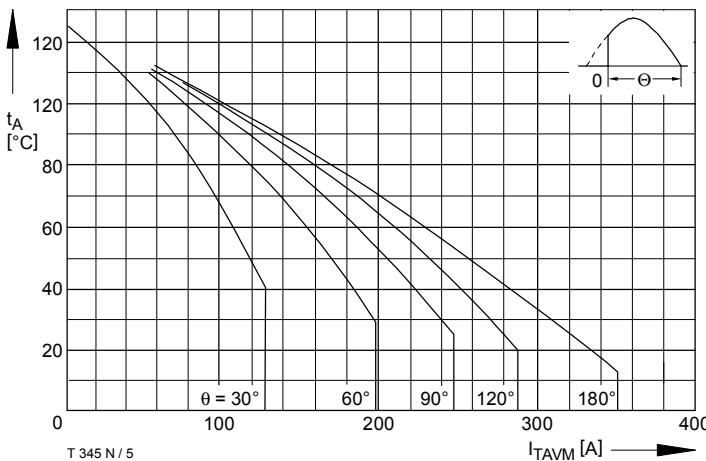


Bild / Fig. 5
Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $t_A = f(I_{TAVM})$
Verstärkte Luftkühlung / Forced air cooling
Kühlkörper / Heatsink: KO.55-FB.54-A, $V_L = 50$ l/s
Parameter: Stromflußwinkel / Current conduction angle θ

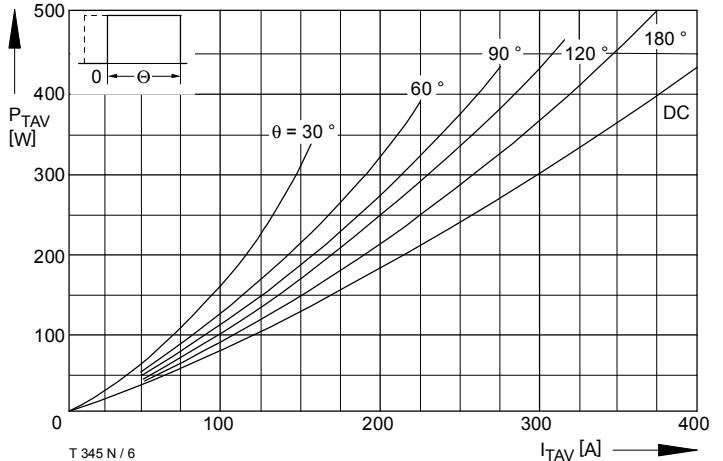
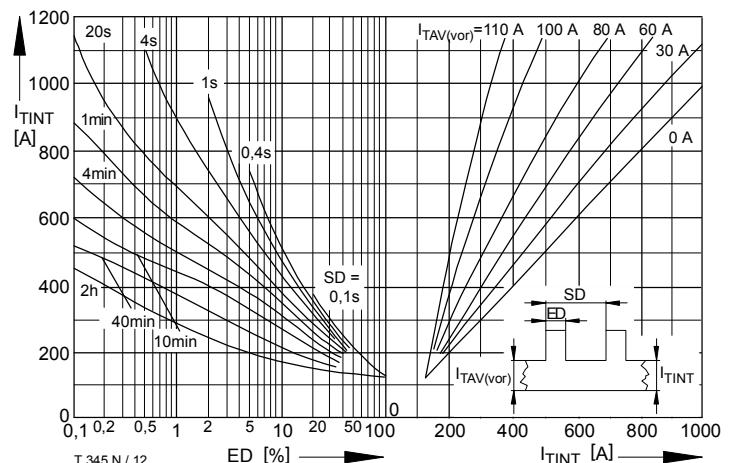
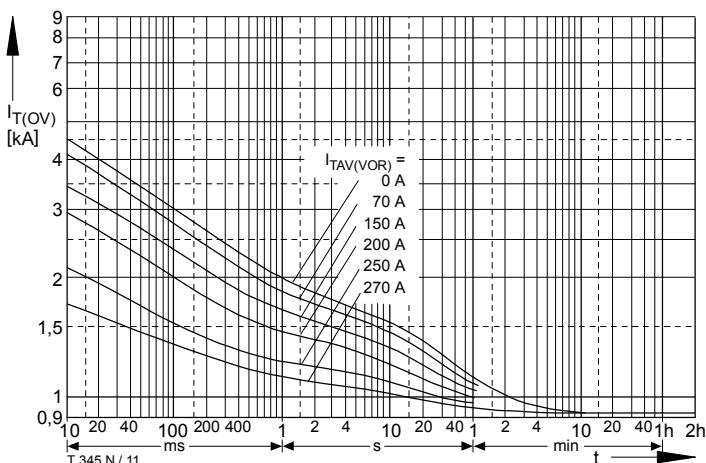
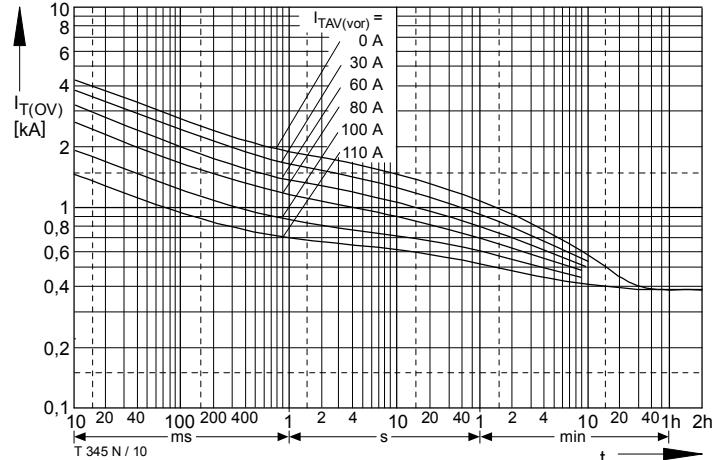
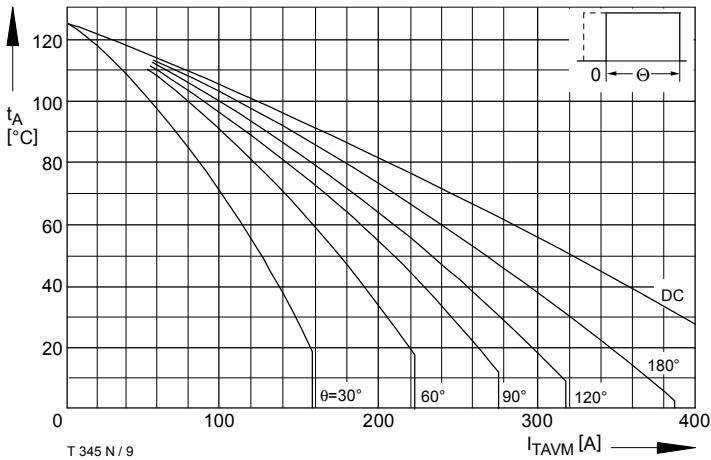
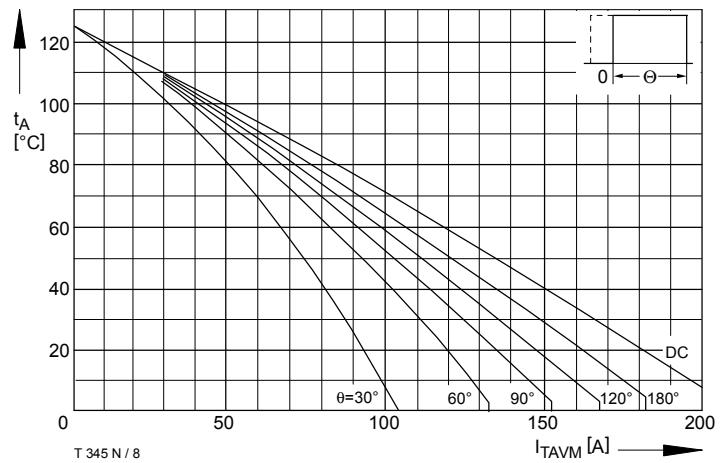
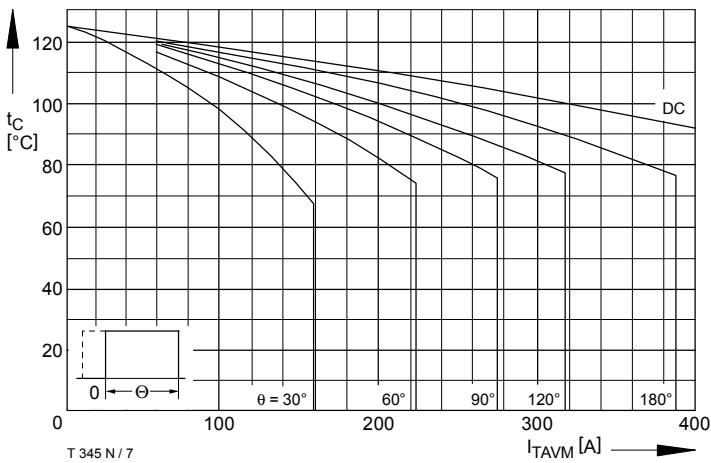


Bild / Fig. 6
Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
Parameter: Stromflußwinkel / Current conduction angle θ



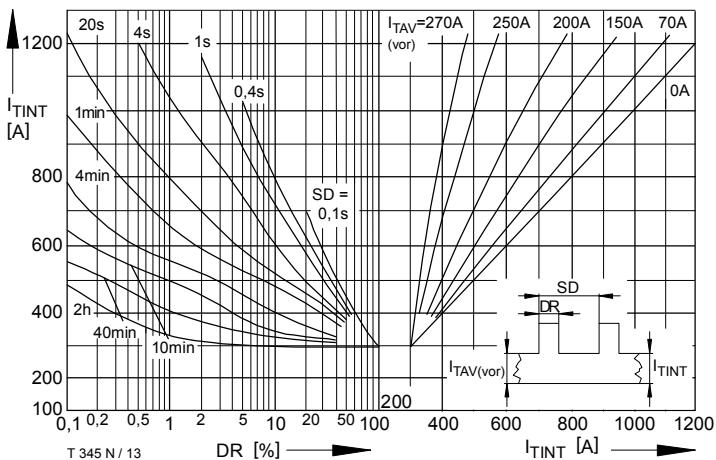


Bild / Fig. 13
Höchstzulässiger Durchlaßstrom bei Aussetzbetrieb / Max. allowable on-state current at intermittent operation $I_{TINT} = f(ED)$
Verstärkte Luftkühlung / Forced air-cooling, $t_A = 35^\circ\text{C}$
Kühlkörper / Heatsink: K0.55-FB54-A, $V_L = 50 \text{ l/s}$
Parameter: Spieldauer / Cycle duration SD
Vorlaststrom / Pre-load current $I_{TAV}(\text{vor})$

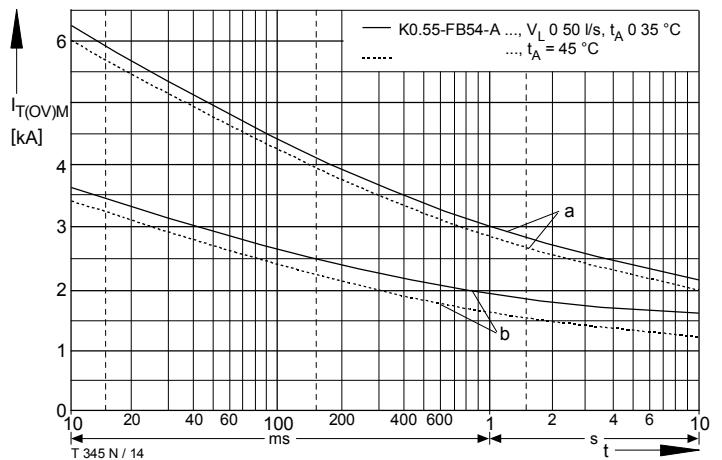


Bild / Fig. 14
Grenzstrom / Max. overload on-state current $I_{T(OV)M} = f(t), V_{RM} = 0,8 V_{RRM}$
— Luftselbstkühlung / Natural air-cooling, $t_A = 45^\circ\text{C}$
— Verstärkte Luftkühlung / Forced air-cooling, $t_A = 35^\circ\text{C}$
Kühlkörper / Heatsink: K0.55-FB54-A, $V_L = 50 \text{ l/s}$
Belastung aus / Surge current occurs:
a - Leerlauf / No-load conditions
b - Betrieb mit Dauergrenzstrom / During operation at max. average on-state current I_{TAVM}

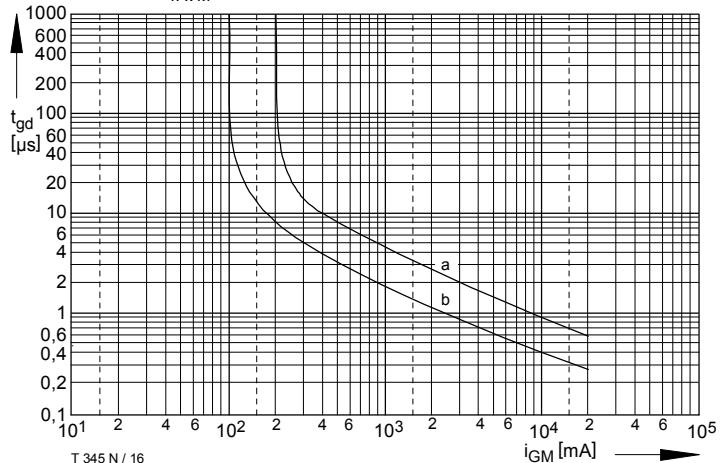


Bild / Fig. 15
Steuercharakteristik mit Zündbereichen / Gate characteristic with triggering areas $v_G = f(i_G), V_D = 6 \text{ V}$
Parameter: a b c d
Steuerimpulsdauer / trigger pulse duration t_g [ms] 10 1 0,5 0,1
Höchstzulässige Spitzensteuerverlustleistung /
Max. rated peak gate power dissipation [W] 40 80 100 150

Bild / Fig. 16
Zündverzug / Gate controlled delay time $t_{gd} = f(i_{GM})$

$t_{vj} = 25^\circ\text{C}, di_G/dt = i_{GM}/1\mu\text{s}$
a - Maximaler Verlauf / Limiting characteristic
b - Typischer Verlauf / Typical characteristic

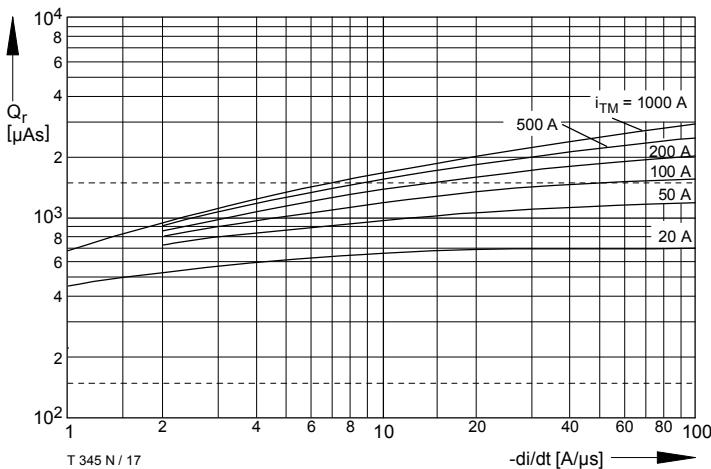
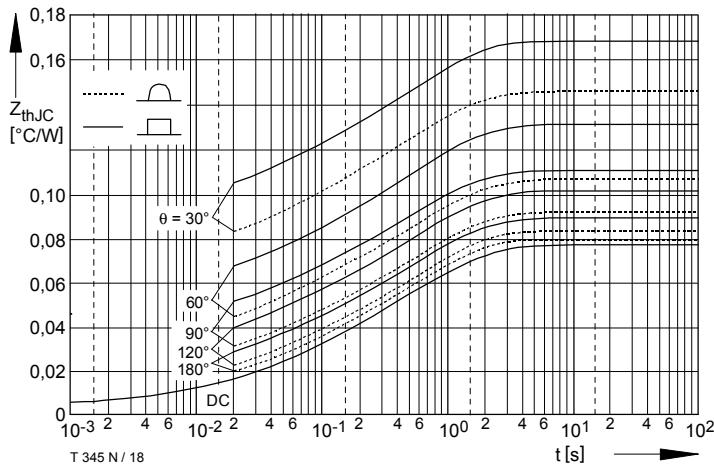


Bild / Fig. 17
Sperrverzögerungsladung / Recovered charge $Q_r = f(di/dt)$
 $t_{vj} = t_{vj \text{ max}}, V_R = 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$
Parameter: Durchlaßstrom / On-state current i_{TM}



Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} pro Zweig für DC
Analytical elements of transient thermal impedance Z_{thJC} per arm for DC

Pos. n	1	2	3	4
$R_{thn} [\text{°C/W}]$	0,0106	0,014	0,0168	0,036
$\tau_n [s]$	0,00117	0,0405	0,222	0,84

Analytische Funktion / Analytical function:

$$Z_{thJC} = \sum_{n=1}^{n_{\max}} R_{thn} (1 - e^{-\frac{t}{\tau_n}})$$